



SamHop Microelectronics Corp.

**STT3414**

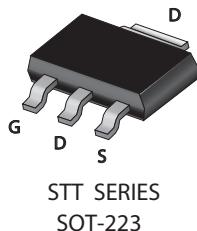
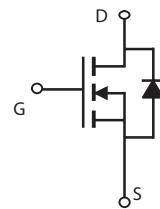
Ver 1.0

N-Channel Logic Level Enhancement Mode Field Effect Transistor

PRODUCT SUMMARY		
VDSS	ID	RDS(ON) (mΩ) Max
30V	7A	33 @ VGS=10V
		42 @ VGS=4.5V
		57 @ VGS=2.5V

FEATURES

- Super high dense cell design for low RDS(ON).
- Rugged and reliable.
- Surface Mount Package.

STT SERIES
SOT-223

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Limit	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	± 12	V
I_D	Drain Current-Continuous ^a	7	A
		5.6	A
I_{DM}	-Pulsed ^b	28	A
E_{AS}	Single Pulse Avalanche Energy ^d	9	mJ
P_D	Maximum Power Dissipation ^a	3	W
		1.9	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 to 150	$^\circ\text{C}$

THERMAL CHARACTERISTICS

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient ^a	42	$^\circ\text{C/W}$
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Details are subject to change without notice.

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ELECTRICAL CHARACTERISTICS ($T_A=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Units
OFF CHARACTERISTICS						
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V, I_D=250\mu A$	30			V
$I_{DS(on)}$	Zero Gate Voltage Drain Current	$V_{DS}=24V, V_{GS}=0V$			1	μA
I_{GSS}	Gate-Body Leakage Current	$V_{GS} = \pm 12V, V_{DS}=0V$			± 100	nA
ON CHARACTERISTICS						
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu A$	0.5	0.9	1.5	V
$R_{DS(on)}$	Drain-Source On-State Resistance	$V_{GS}=10V, I_D=3.5A$		26	33	m ohm
		$V_{GS}=4.5V, I_D=3.1A$		31	42	m ohm
		$V_{GS}=2.5V, I_D=2.6A$		42	57	m ohm
g_{FS}	Forward Transconductance	$V_{DS}=5V, I_D=3.5A$		16		S
DYNAMIC CHARACTERISTICS ^c						
C_{iss}	Input Capacitance	$V_{DS}=15V, V_{GS}=0V$ $f=1.0MHz$		390		pF
C_{oss}	Output Capacitance			69		pF
C_{rss}	Reverse Transfer Capacitance			56		pF
SWITCHING CHARACTERISTICS ^c						
$t_{D(ON)}$	Turn-On Delay Time	$V_{DD}=15V$ $I_D=1A$ $V_{GS}=10V$ $R_{GEN}=6\text{ ohm}$		6.6		ns
t_r	Rise Time			11		ns
$t_{D(OFF)}$	Turn-Off Delay Time			18		ns
t_f	Fall Time			16		ns
Q_g	Total Gate Charge	$V_{DS}=15V, I_D=3.5A, V_{GS}=10V$		9.8		nC
		$V_{DS}=15V, I_D=3.5A, V_{GS}=4.5V$		5		nC
Q_{gs}	Gate-Source Charge	$V_{DS}=15V, I_D=3.5A,$ $V_{GS}=10V$		0.7		nC
Q_{gd}	Gate-Drain Charge			2		nC
DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS						
V_{SD}	Diode Forward Voltage	$V_{GS}=0V, I_S=1A$		0.77	1.2	V
Notes						
a. Surface Mounted on FR4 Board, $t \leq 10\text{sec}$.						
b. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.						
c. Guaranteed by design, not subject to production testing.						
d. Starting $T_J=25^\circ C, L=0.5\text{mH}, V_{DD}=20V$. (See Figure13)						

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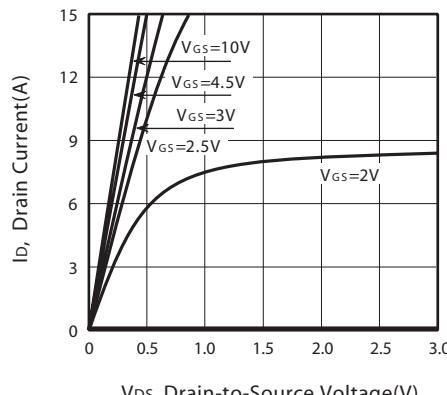


Figure 1. Output Characteristics

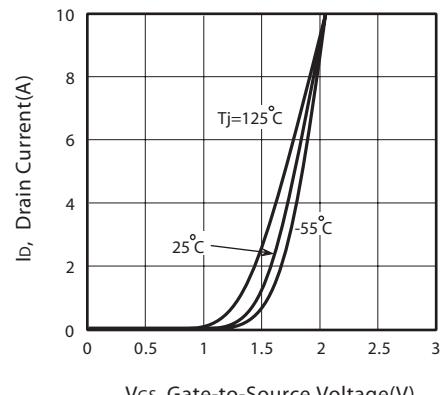


Figure 2. Transfer Characteristics

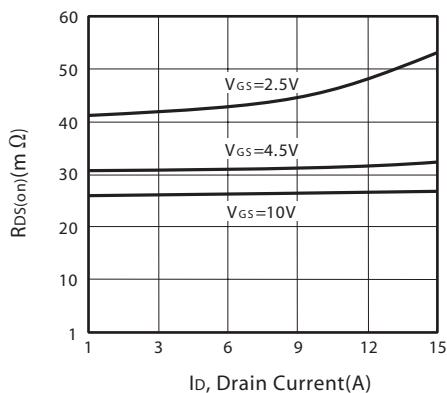


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

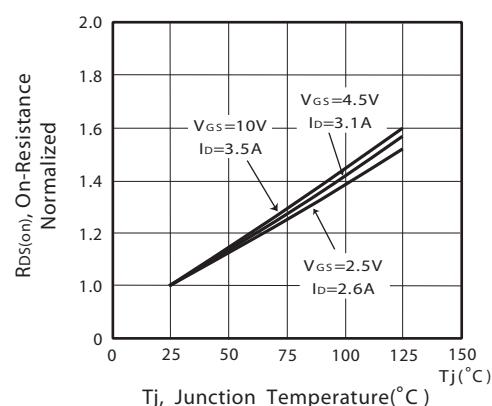


Figure 4. On-Resistance Variation with Drain Current and Temperature

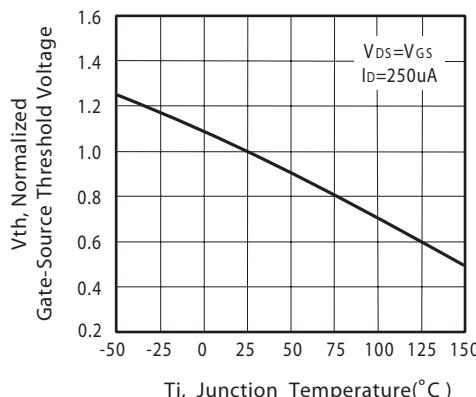


Figure 5. Gate Threshold Variation with Temperature

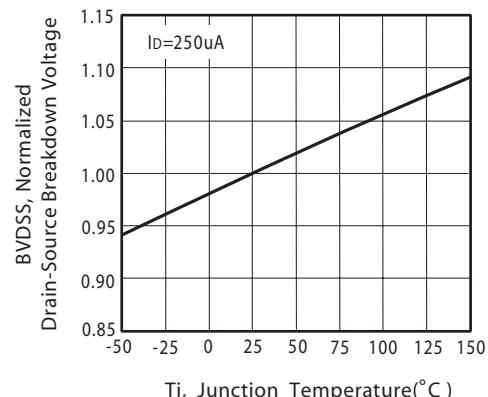
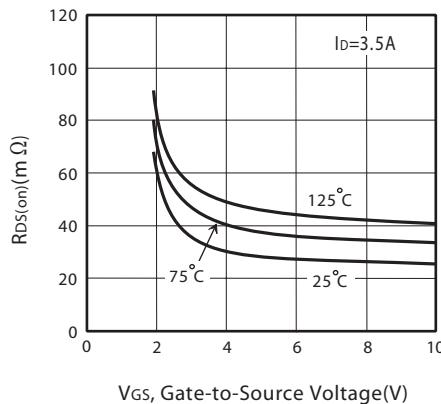


Figure 6. Breakdown Voltage Variation with Temperature

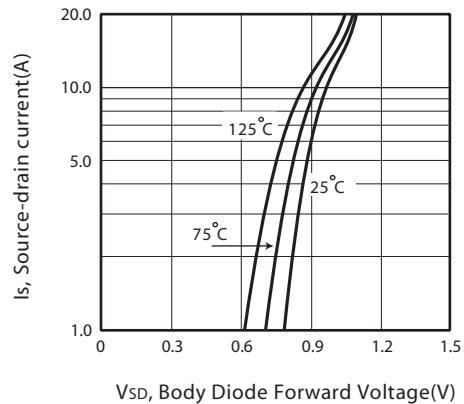
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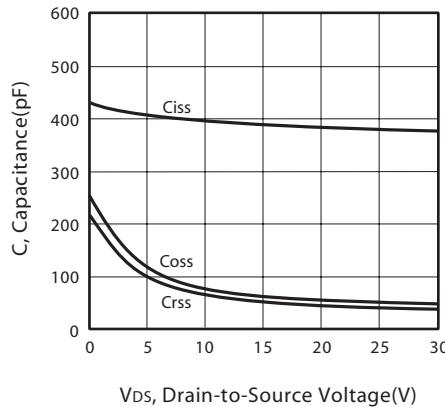
V_{GS}, Gate-to-Source Voltage(V)

Figure 7. On-Resistance vs. Gate-Source Voltage



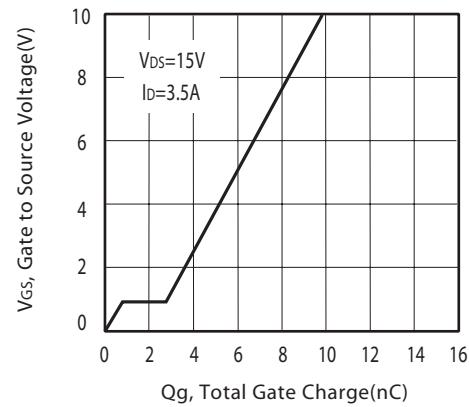
V_{SD}, Body Diode Forward Voltage(V)

Figure 8. Body Diode Forward Voltage Variation with Source Current



V_{DS}, Drain-to-Source Voltage(V)

Figure 9. Capacitance



Q_g, Total Gate Charge(nC)

Figure 10. Gate Charge

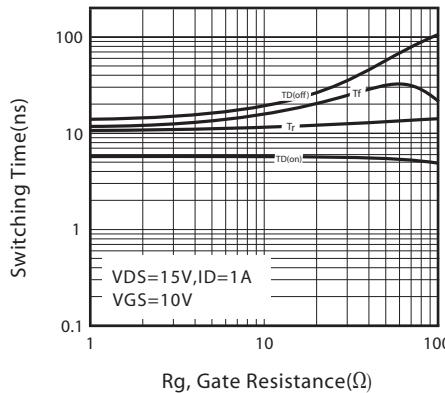


Figure 11. switching characteristics

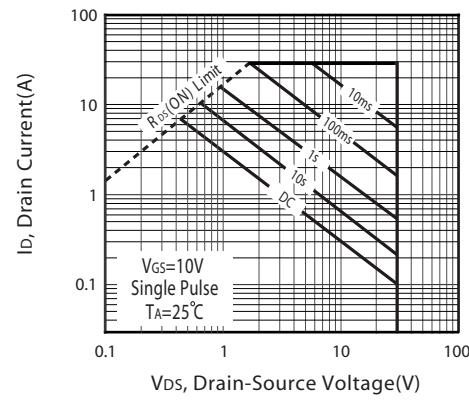
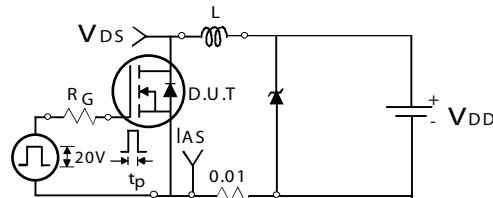


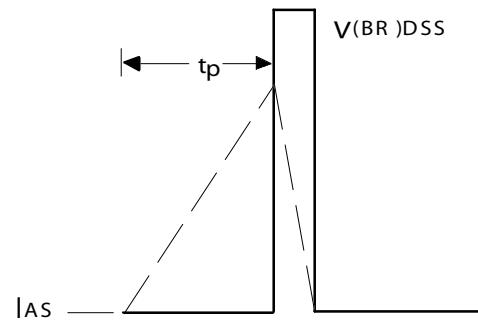
Figure 12. Maximum Safe Operating Area

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Unclamped Inductive Test Circuit

Figure 13a.



Unclamped Inductive Waveforms

Figure 13b.

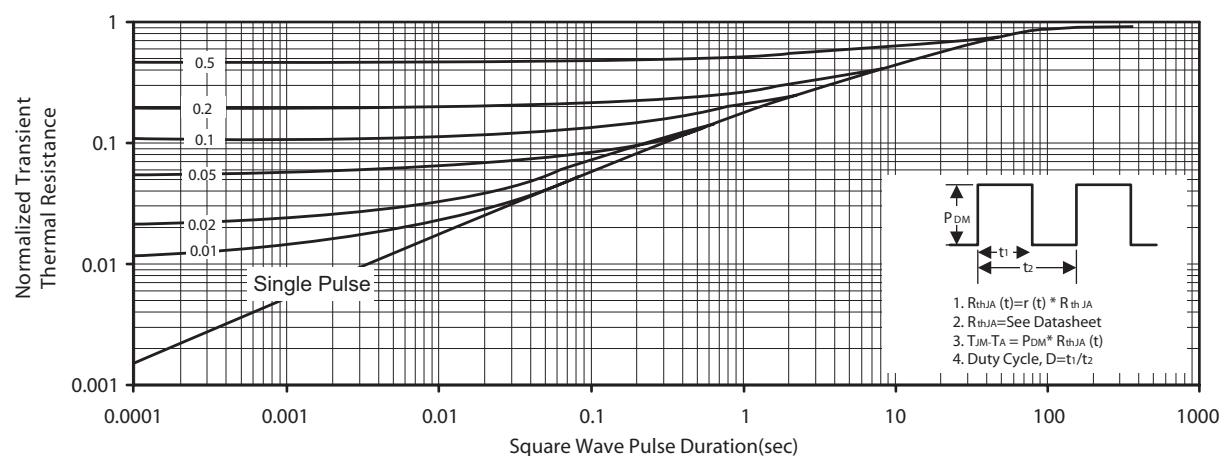
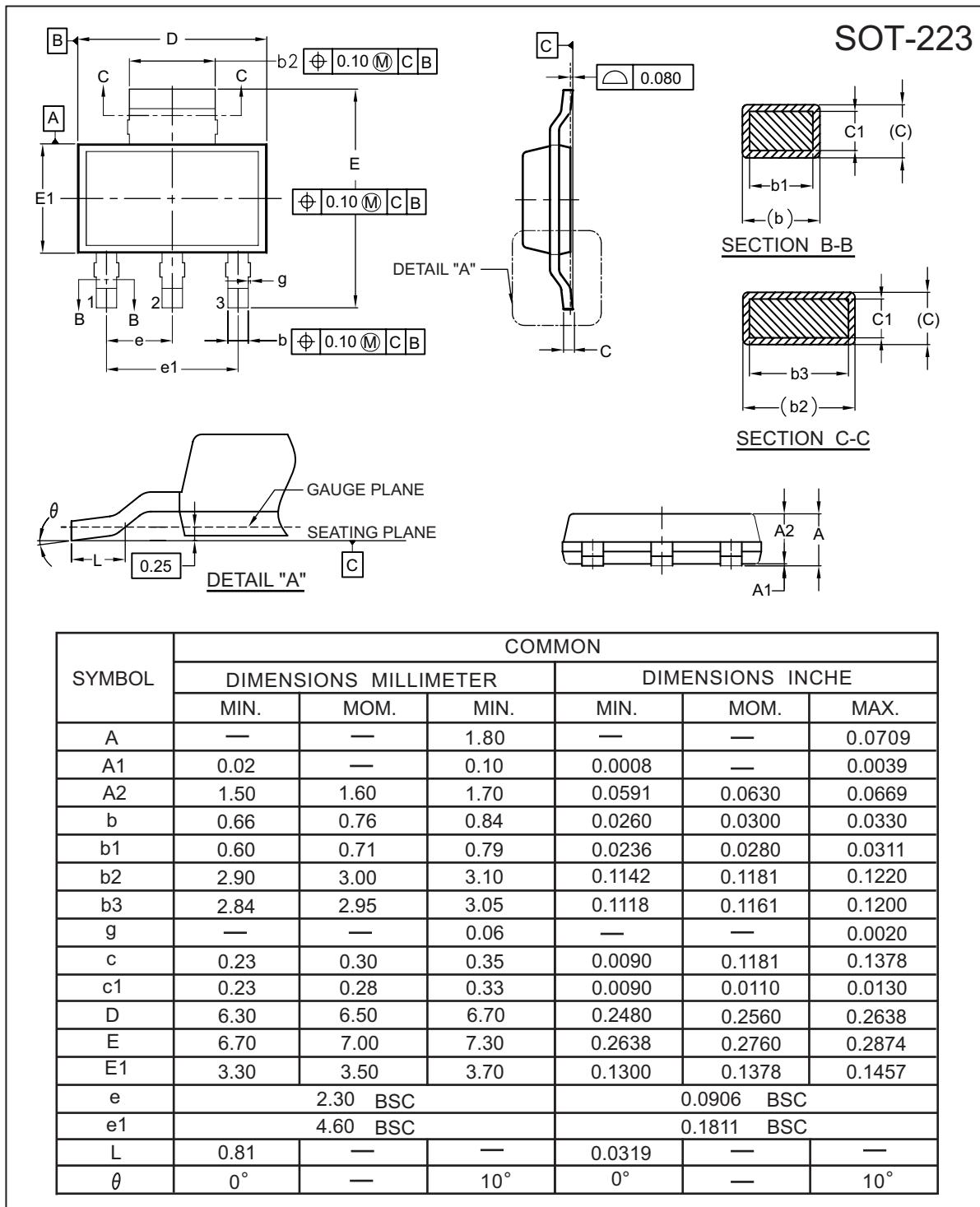


Figure 14. Normalized Thermal Transient Impedance Curve

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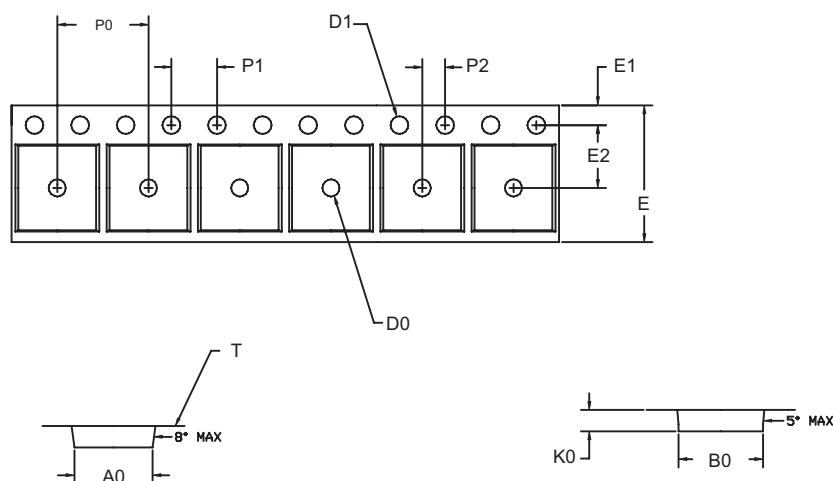
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SOT-223 Tape and Reel Data

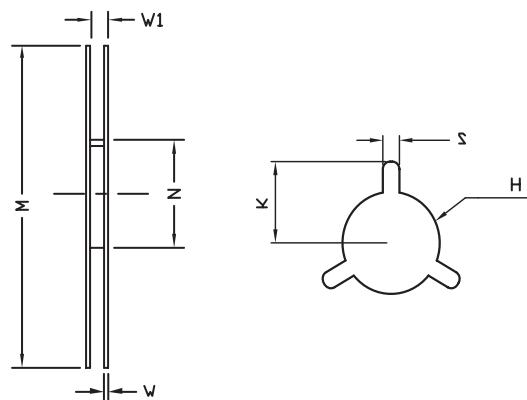
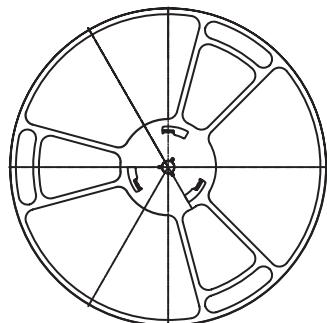
SOT-223 Carrier Tape



unit:mm

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
---	6.83 ±0.1	7.42 ±0.1	1.88 ±0.1	1.50 + 0.25	1.60 + 0.1	12.0 + 0.3 - 0.1	1.75 ±0.1	5.50 ±0.5	8.0 ±0.1	4.00 ±0.1	2.00 ±0.05	0.292 ±0.02

SOT-223 Reel



UNIT:mm

REEL SIZE	M	N	W	W1	H	K	S	G	R	V
φ 330 ± 0.5	---	φ 97.0 ± 1.0	2.2	13.0 + 1.5	φ 13.0 + 0.5 - 0.2	10.6	2.0 ± 0.5	---	---	---